

**NOT RECOMMENDED FOR NEW DESIGNS**

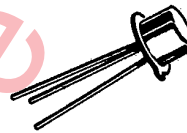
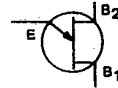
## PN Unijunction Transistors Silicon Unijunction Transistors

... designed for pulse and timing circuits, sensing circuits, and thyristor trigger circuits.

- Low Peak-Point Current —  $I_p = 0.4 \mu\text{A Max}$
- Low Emitter Reverse Current —  $I_{EO} = 50 \text{ nA Max}$
- Fast Switching

**2N4851  
thru  
2N4853**

PN UJT's



CASE 22A-01  
STYLE 1

\*MAXIMUM RATINGS ( $T_A = 25^\circ\text{C}$  unless otherwise noted.)

Rating	Symbol	Value	Unit
RMS Power Dissipation, Note 1	$P_D$	300	mW
RMS Emitter Current	$I_e$	50	mA
Peak-Pulse Emitter Current, Note 2	$I_e$	1.5	Amp
Emitter Reverse Voltage	$V_{B2E}$	30	Volts
Interbase Voltage, Note 3	$V_{B2B1}$	35	Volts
Operating Junction Temperature Range	$T_J$	-65 to +125	$^\circ\text{C}$
Storage Temperature Range	$T_{stg}$	-65 to +200	$^\circ\text{C}$

\*Indicates JEDEC Registered Data.

- Notes: 1. Derate 3 mW/ $^\circ\text{C}$  increase in ambient temperature.  
 2. Duty cycle  $\leq 1\%$ , PRR = (see Figure 6).  
 3. Based upon power dissipation at  $T_A = 25^\circ\text{C}$ .

3

ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C unless otherwise noted.)

Rating	Fig. No.	Symbol	Min	Typ	Max	Unit
*Intrinsic Standoff Ratio, Note 1 (V <sub>B2B1</sub> = 10 V)	4, 8	η	0.56 0.70	—	0.75 0.85	—
*Interbase Resistance (V <sub>B2B1</sub> = 3 V, I <sub>E</sub> = 0)	11, 12	r <sub>BB</sub>	4.7	—	9.1	k ohms
*Interbase Resistance Temperature Coefficient (V <sub>B2B1</sub> = 3 V, I <sub>E</sub> = 0, T <sub>A</sub> = -65 to +125°C)	12	α <sub>BB</sub>	0.2	—	0.8	%/°C
Emitter Saturation Voltage, Note 2 (V <sub>B2B1</sub> = 10 V, I <sub>E</sub> = 50 mA)		V <sub>EB1(sat)</sub>	—	2.5	—	Volts
Modulated Interbase Current (V <sub>B2B1</sub> = 10 V, I <sub>E</sub> = 50 mA)		I <sub>B2(mod)</sub>	—	15	—	mA
*Emitter Reverse Current (V <sub>B2E</sub> = 30 V, I <sub>B1</sub> = 0)	7	I <sub>EB20</sub>	—	—	0.1 0.05	μA
*Peak-Point Emitter Current (V <sub>B2B1</sub> = 25 V)	9, 10	I <sub>p</sub>	—	—	2 0.4	μA
*Valley-Point Current, Note 2 (V <sub>B2B1</sub> = 20 V, R <sub>B2</sub> = 100 ohms)	13, 14	I <sub>v</sub>	2 4 6	— — —	— — —	mA
*Base-One Peak Pulse Voltage	2N4851 2N4852 2N4853	V <sub>OB1</sub>	3 5 6	— — —	— — —	Volts
*Maximum Frequency of Oscillation	5	f <sub>(max)</sub>	—	0.25	—	MHz

3

\*Indicates JEDEC Registered Data.

Notes: 1. η, Intrinsic standoff ratio, is defined in terms of the peak-point voltage, V<sub>p</sub>, by means of the equation: V<sub>p</sub> = η V<sub>B2B1</sub> + V<sub>F</sub>, where V<sub>F</sub> is about 0.49 volt at 25°C @ I<sub>F</sub> = 10 μA and decreases with temperature at about 2.5 mV/°C. The test circuit is shown in Figure 4. Components R<sub>1</sub>, C<sub>1</sub>, and the UJT form a relaxation oscillator; the remaining circuitry serves as a peak-voltage detector. The forward drop of Diode D<sub>1</sub> compensates for V<sub>F</sub>. To use, the "cal" button is pushed, and R<sub>3</sub> is adjusted to make the current meter, M<sub>1</sub>, read full scale. When the "cal" button is released, the value of η is read directly from the meter, if full scale on the meter reads 1.

2. Use pulse techniques: PW ≈ 300 μs, duty cycle ≤ 2% to avoid internal heating, which may result in erroneous readings.

FIGURE 1 - UNIJUNCTION TRANSISTOR SYMBOL AND NOMENCLATURE

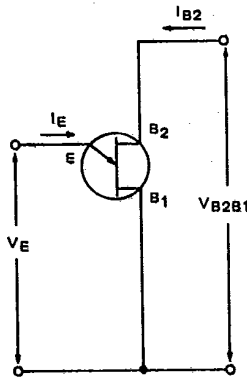


FIGURE 2 - STATIC EMITTER CHARACTERISTICS CURVES

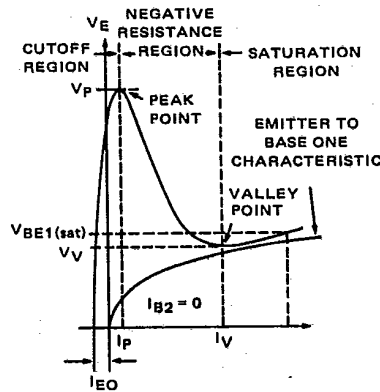


FIGURE 3 -  $V_{OB1}$  TEST CIRCUIT

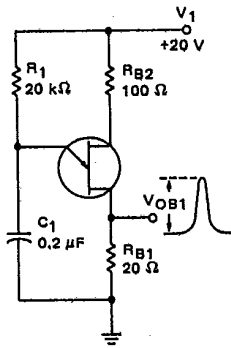


FIGURE 5 -  $f_{(max)}$  TEST CIRCUIT

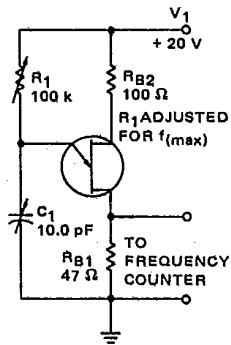


FIGURE 4 -  $\eta$  TEST CIRCUIT.

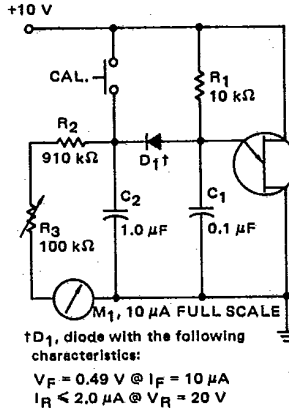
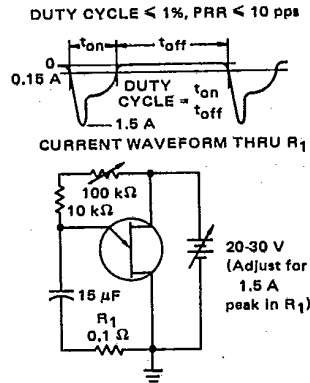


FIGURE 6 - PRR TEST CIRCUIT AND WAVEFORM



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TYPICAL CHARACTERISTICS

FIGURE 7 - EMITTER REVERSE CURRENT

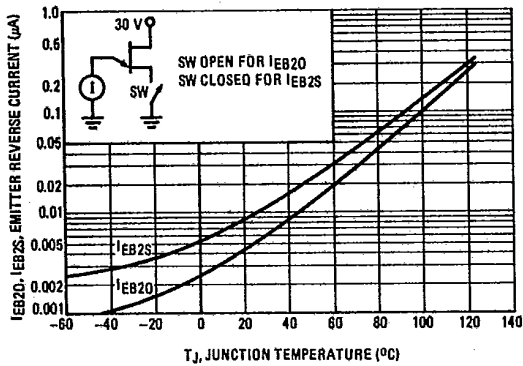
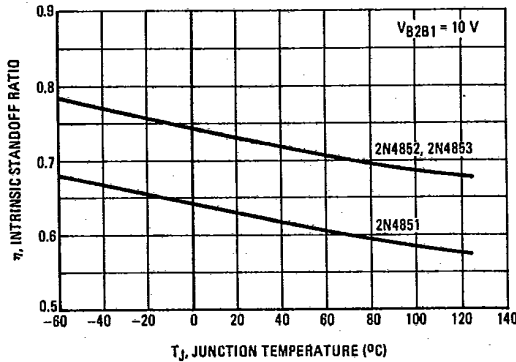


FIGURE 8 - INTRINSIC STANDOFF RATIO



2N4851 thru 2N4853

T-37-21

PEAK POINT CURRENT

FIGURE 9 - EFFECT OF VOLTAGE

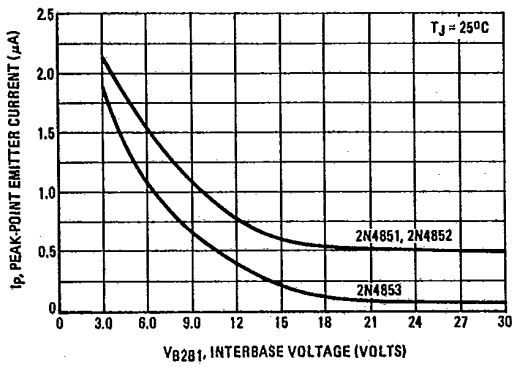
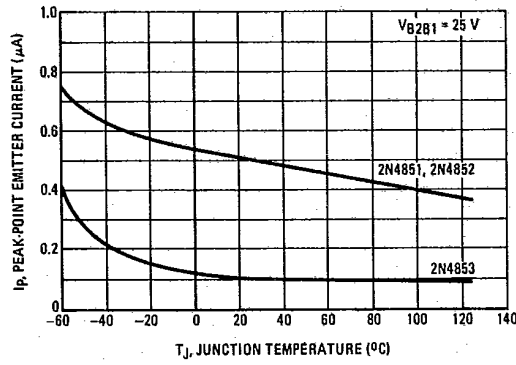


FIGURE 10 - EFFECT OF TEMPERATURE



INTERBASE RESISTANCE

FIGURE 11 - EFFECT OF VOLTAGE

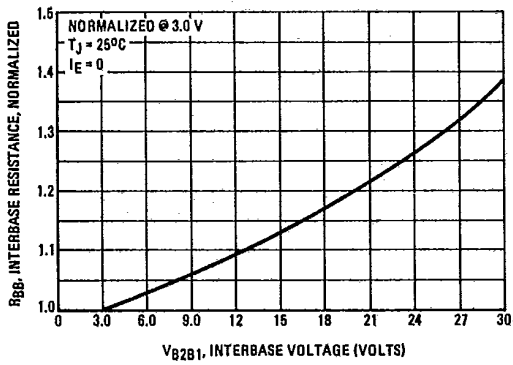
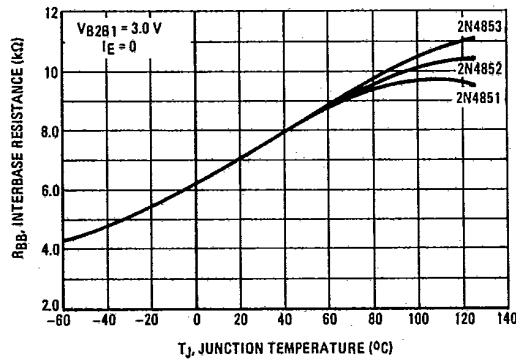


FIGURE 12 - EFFECT OF TEMPERATURE



TYPICAL CHARACTERISTICS

VALLEY CURRENT

FIGURE 13 - EFFECT OF VOLTAGE

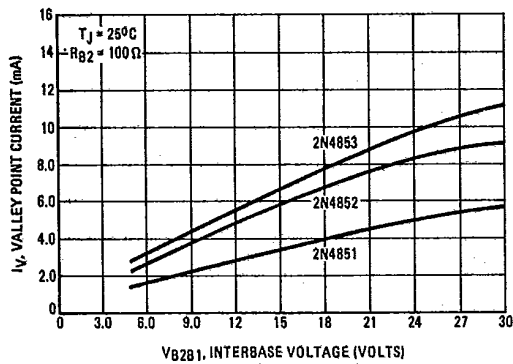
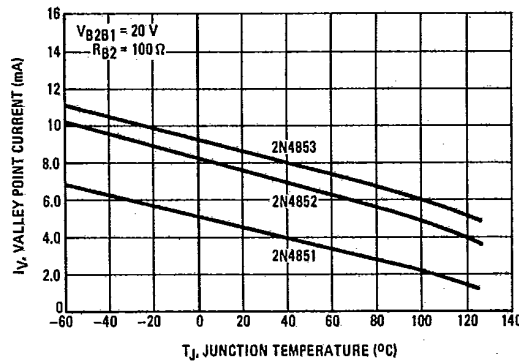


FIGURE 14 - EFFECT OF TEMPERATURE



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2N4851 thru 2N4853

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VALLEY VOLTAGE

FIGURE 15 - EFFECT OF VOLTAGE

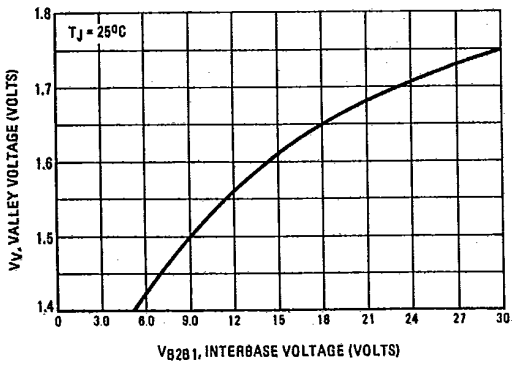


FIGURE 16 - EFFECT OF TEMPERATURE

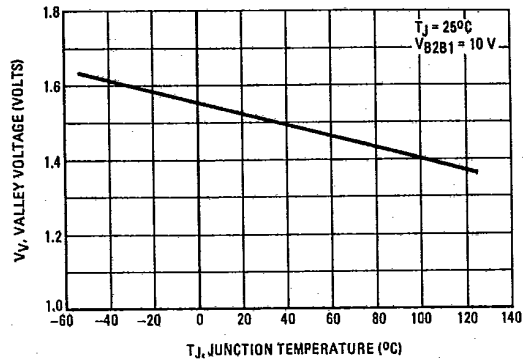
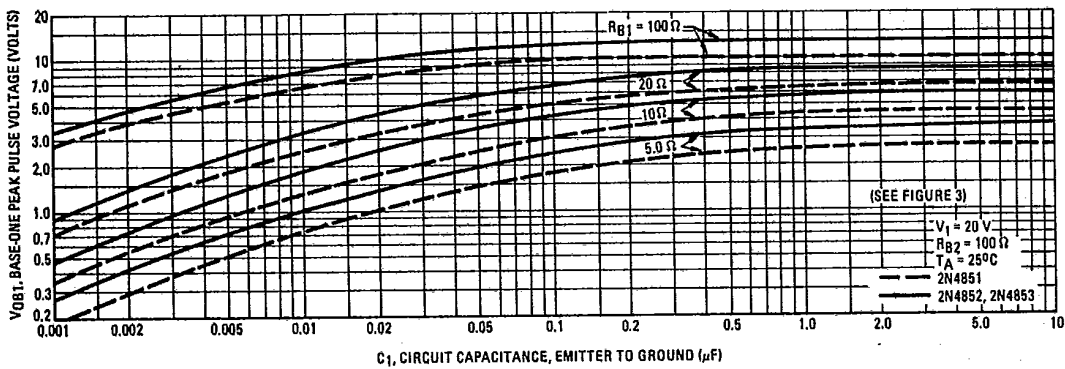


FIGURE 17 - OUTPUT VOLTAGE



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